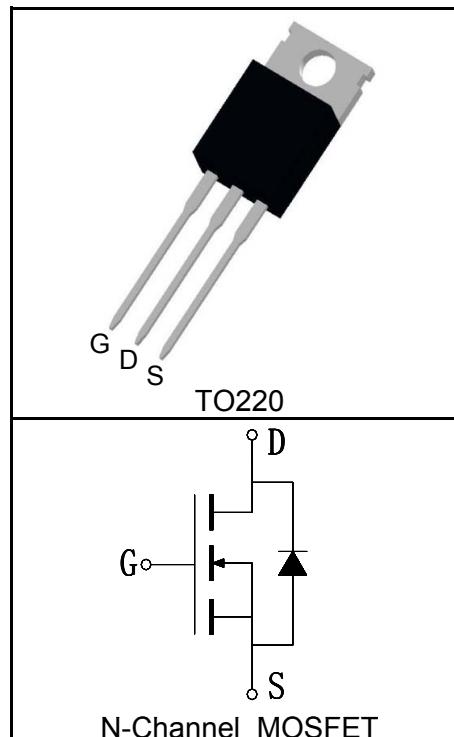


**Features**

- 150V/120A,  $R_{DS(ON)} = 11\text{m}\Omega$ (Typ.)@ $V_{GS}=10\text{V}$
- Reliable and Rugged
- 100% avalanche tested
- 175°C Operating Temperature
- Lead Free and Green Devices Available (RoHS Compliant)

**Pin Description****Applications**

- High Speed Power Switching
- High Efficiency Synchronous in SMPS
- Automotive applications and a wide variety of other applications

**Absolute Maximum Ratings**

Symbol	Parameter	Rating	Unit
<b>Common Ratings</b> ( $T_c=25^\circ\text{C}$ Unless Otherwise Noted)			
$V_{DSS}$	Drain-Source Voltage	150	V
$V_{GSS}$	Gate-Source Voltage	$\pm 25$	
$T_J$	Maximum Junction Temperature	175	°C
$T_{STG}$	Storage Temperature Range	-55 to 175	°C
$I_S$	Diode Continuous Forward Current	$T_c=25^\circ\text{C}$	120
<b>Mounted on Large Heat Sink</b>			
$I_{DP}^{①}$	300μs Pulse Drain Current Tested	$T_c=25^\circ\text{C}$	480
$I_D^{②}$	Continuous Drain Current( $V_{GS}=10\text{V}$ )	$T_c=25^\circ\text{C}$	120
		$T_c=100^\circ\text{C}$	85
$P_D$	Maximum Power Dissipation	$T_c=25^\circ\text{C}$	375
		$T_c=100^\circ\text{C}$	188
$R_{\theta JC}$	Thermal Resistance-Junction to Case	0.4	°C/W
$R_{\theta JA}$	Thermal Resistance-Junction to Ambient	62.5	°C/W
<b>Drain-Source Avalanche Ratings</b>			
$E_{AS}^{③}$	Avalanche Energy, Single Pulsed	552	mJ

**Electrical Characteristics** ( $T_C=25^\circ\text{C}$  Unless Otherwise Noted)

Symbol	Parameter	Test Condition	RU1Z120R			Unit
			Min.	Typ.	Max.	
<b>Static Characteristics</b>						
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_{\text{DS}}=250\mu\text{A}$	150			V
$\text{I}_{\text{DSS}}$	Zero Gate Voltage Drain Current	$\text{V}_{\text{DS}}=150\text{V}, \text{V}_{\text{GS}}=0\text{V}$			1	$\mu\text{A}$
		$\text{T}_J=125^\circ\text{C}$			30	
$\text{V}_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_{\text{DS}}=250\mu\text{A}$	2.5	3.1	4.5	V
$\text{I}_{\text{GSS}}$	Gate Leakage Current	$\text{V}_{\text{GS}}=\pm 25\text{V}, \text{V}_{\text{DS}}=0\text{V}$			$\pm 100$	nA
$\text{R}_{\text{DS}(\text{ON})}^{(4)}$	Drain-Source On-state Resistance	$\text{V}_{\text{GS}}=10\text{V}, \text{I}_{\text{DS}}=60\text{A}$		11	15	mΩ
<b>Diode Characteristics</b>						
$\text{V}_{\text{SD}}^{(4)}$	Diode Forward Voltage	$\text{I}_{\text{SD}}=60\text{A}, \text{V}_{\text{GS}}=0\text{V}$			1.2	V
$\text{t}_{\text{rr}}$	Reverse Recovery Time	$\text{I}_{\text{SD}}=60\text{A}, \frac{d\text{I}_{\text{SD}}}{dt}=100\text{A}/\mu\text{s}$		56		ns
$\text{Q}_{\text{rr}}$	Reverse Recovery Charge			102		nC
<b>Dynamic Characteristics</b> <sup>(5)</sup>						
$\text{R}_G$	Gate Resistance	$\text{V}_{\text{GS}}=0\text{V}, \text{V}_{\text{DS}}=0\text{V}, \text{F}=1\text{MHz}$		1.5		Ω
$\text{C}_{\text{iss}}$	Input Capacitance	$\text{V}_{\text{GS}}=0\text{V},$		4900		pF
$\text{C}_{\text{oss}}$	Output Capacitance	$\text{V}_{\text{DS}}=75\text{V},$		1010		
$\text{C}_{\text{rss}}$	Reverse Transfer Capacitance	Frequency=1.0MHz		220		
$\text{t}_{\text{d}(\text{ON})}$	Turn-on Delay Time	$\text{V}_{\text{DD}}=75\text{V}, \text{I}_{\text{DS}}=60\text{A},$ $\text{V}_{\text{GEN}}=10\text{V}, \text{R}_G=6\Omega$		20		ns
$\text{t}_r$	Turn-on Rise Time			98		
$\text{t}_{\text{d}(\text{OFF})}$	Turn-off Delay Time			105		
$\text{t}_f$	Turn-off Fall Time			52		
<b>Gate Charge Characteristics</b> <sup>(5)</sup>						
$\text{Q}_g$	Total Gate Charge	$\text{V}_{\text{DS}}=120\text{V}, \text{V}_{\text{GS}}=10\text{V},$ $\text{I}_{\text{DS}}=60\text{A}$		95		nC
$\text{Q}_{\text{gs}}$	Gate-Source Charge			25		
$\text{Q}_{\text{gd}}$	Gate-Drain Charge			30		

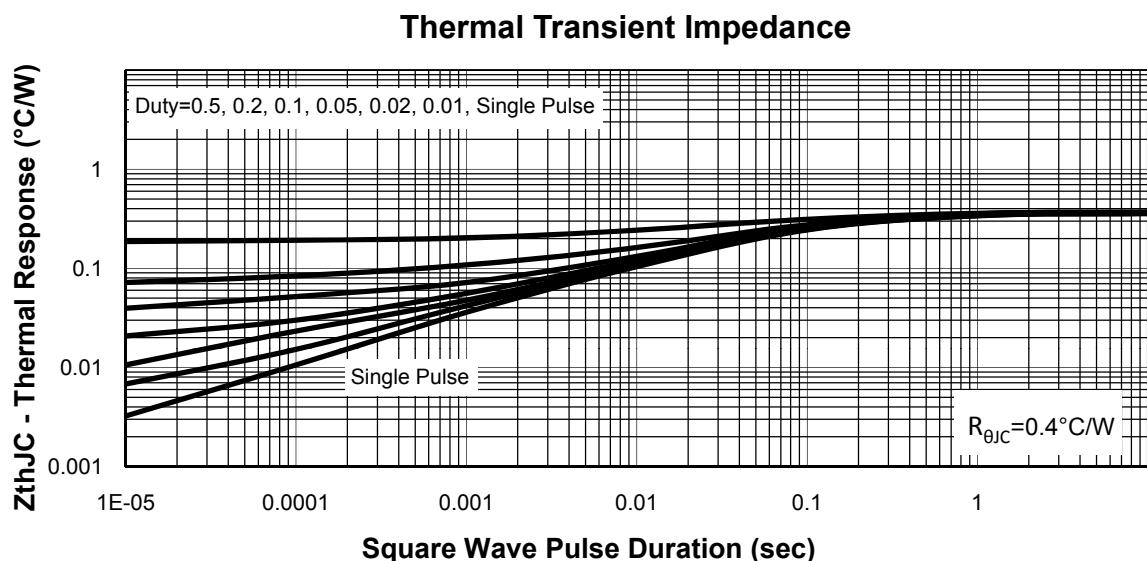
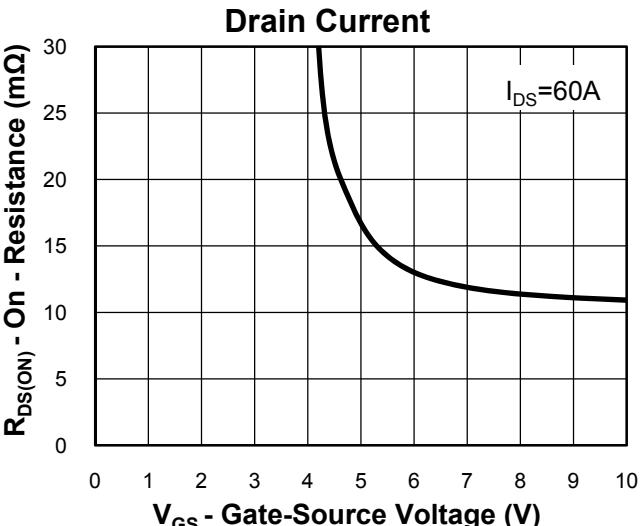
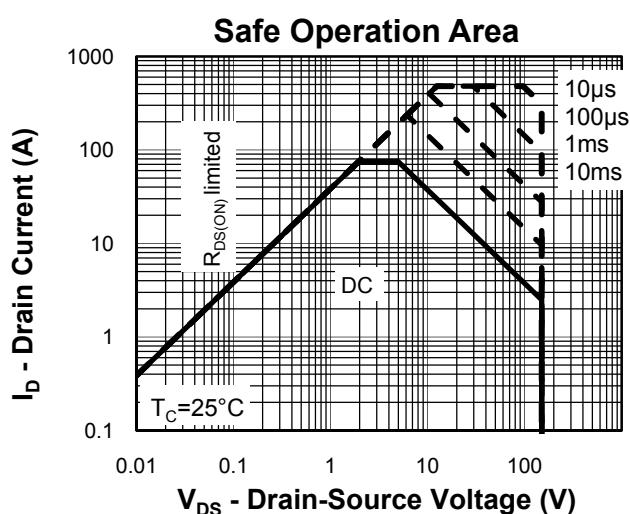
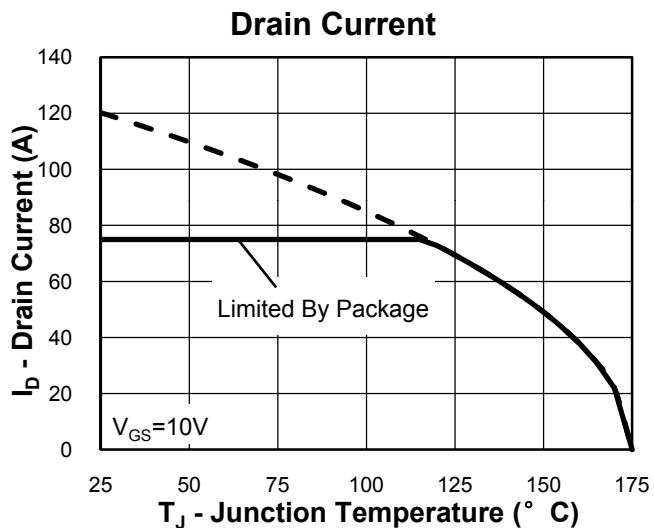
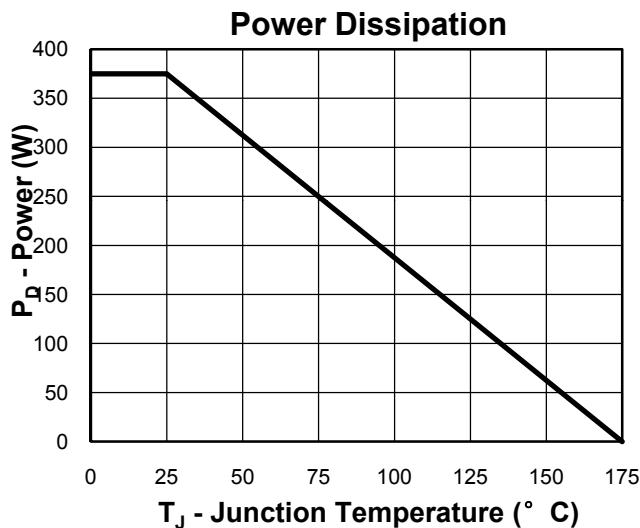
Notes:

- (1)Pulse width limited by safe operating area.
- (2)Calculated continuous current based on maximum allowable junction temperature. The package limitation current is 75A.
- (3)Limited by  $\text{T}_{\text{Jmax}}, \text{I}_{\text{AS}} = 47\text{A}, \text{V}_{\text{DD}} = 48\text{V}, \text{R}_G = 50\Omega$ , Starting  $\text{T}_J = 25^\circ\text{C}$ .
- (4)Pulse test; Pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .
- (5)Guaranteed by design, not subject to production testing.

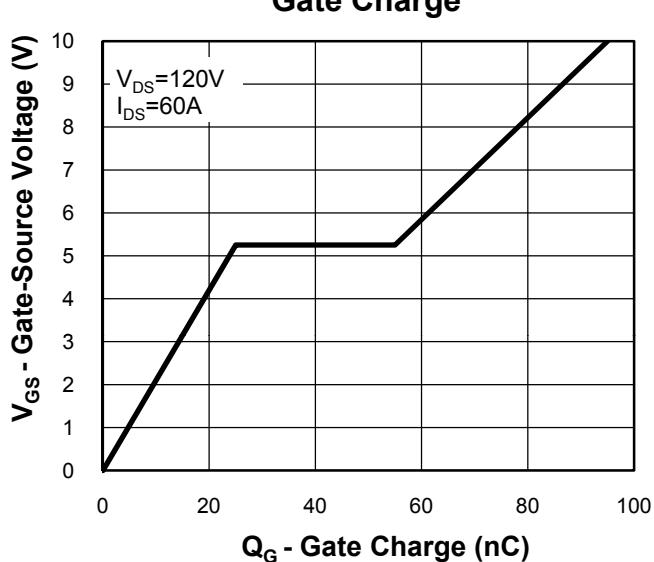
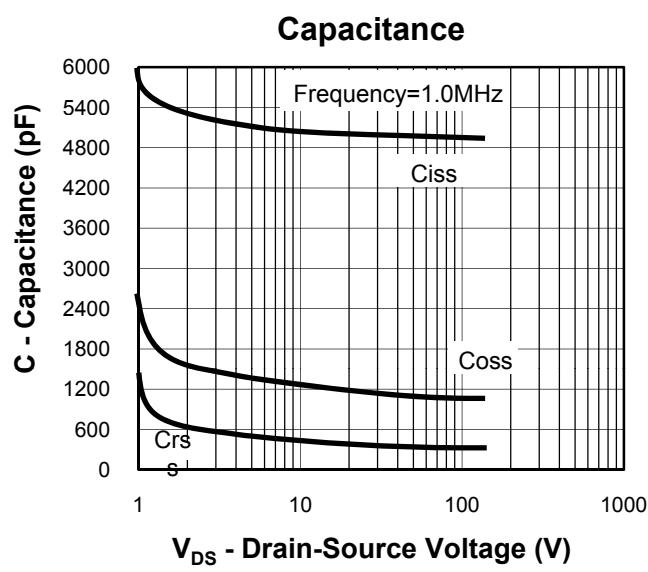
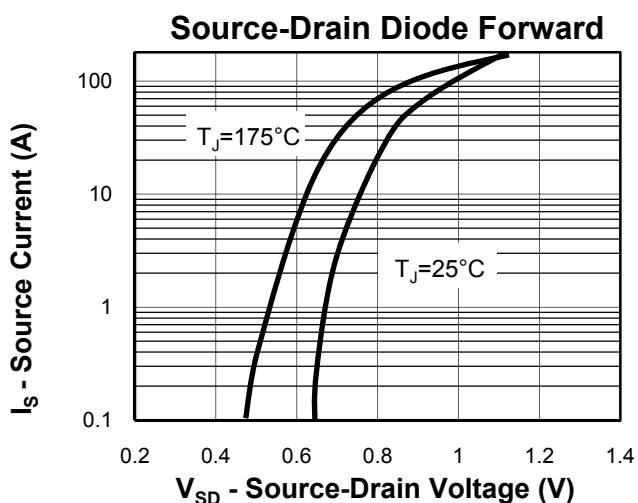
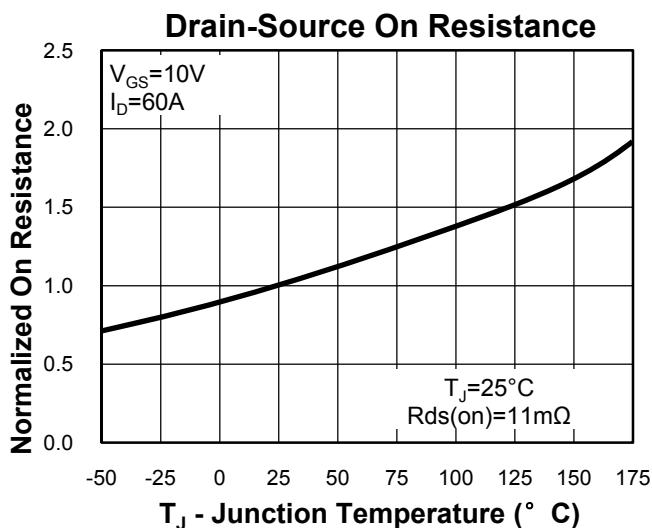
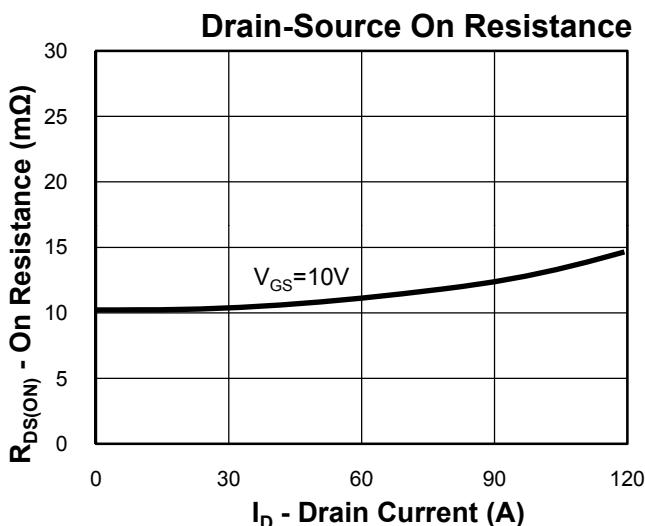
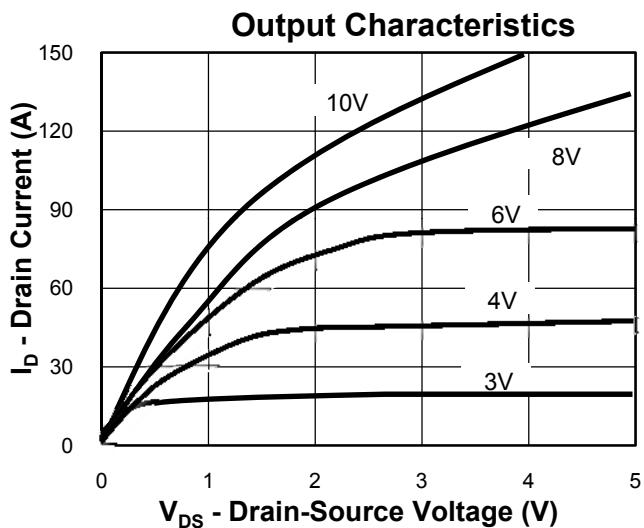
## Ordering and Marking Information

Device	Marking	Package	Packaging	Quantity	Reel Size	Tape width
RU1Z120R	RU1Z120R	TO220	Tube	50	-	-

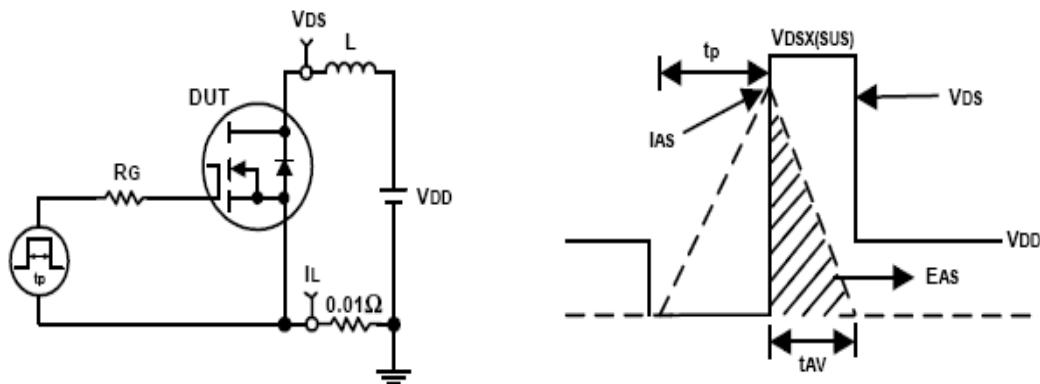
### Typical Characteristics



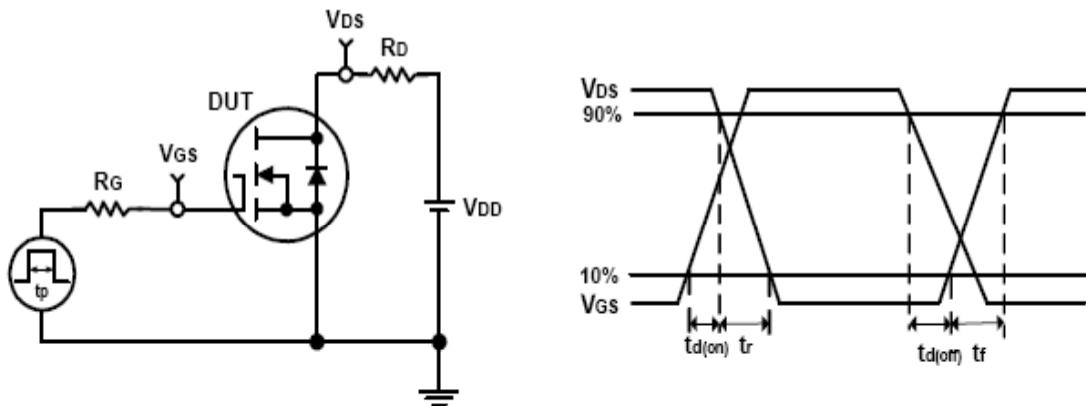
### Typical Characteristics



### Avalanche Test Circuit and Waveforms

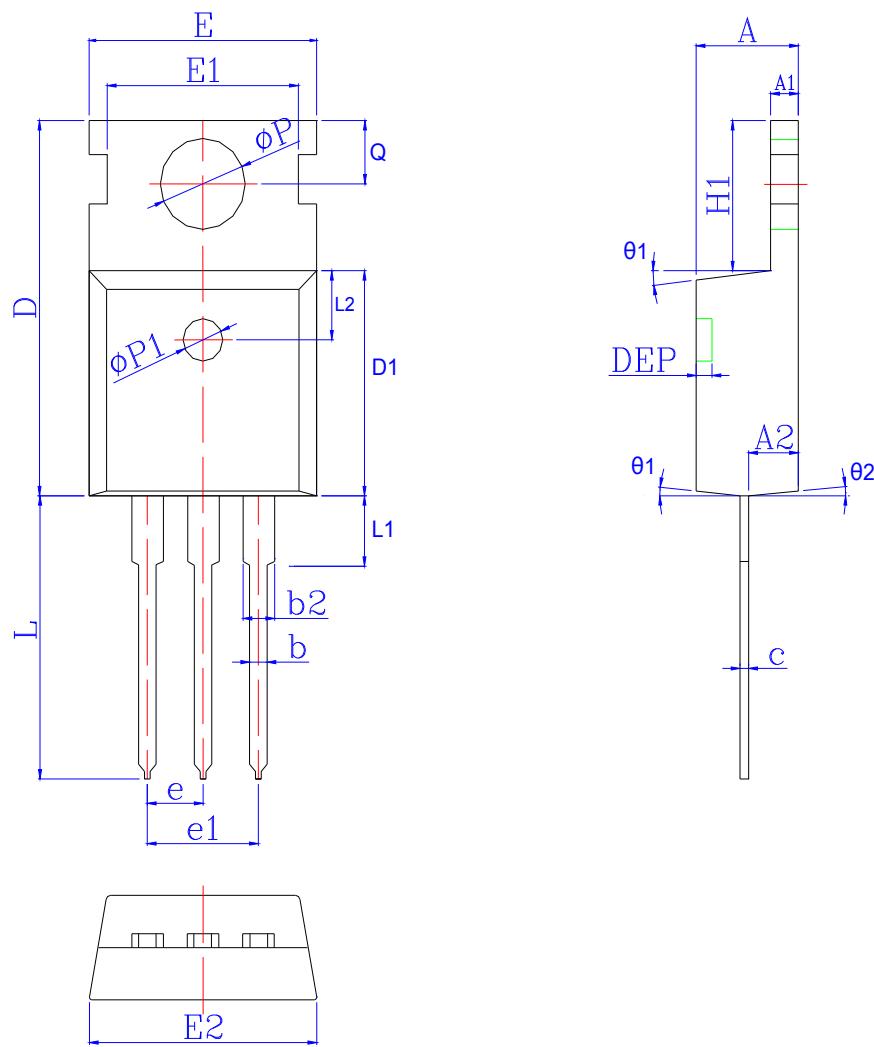


### Switching Time Test Circuit and Waveforms



## Package Information

TO220



SYMBOL	MM			INCH			SYMBOL	MM			INCH		
	MIN	NOM	MAX	MIN	NOM	MAX		MIN	NOM	MAX	MIN	NOM	MAX
A	4.30	4.50	4.70	0.169	0.177	0.185	Φp1	1.40	1.50	1.60	0.055	0.059	0.063
A1	1.15	1.30	1.40	0.045	0.051	0.055	e	2.54 BSC			0.10 BSC		
A2	1.90	2.25	2.60	0.075	0.089	0.102	e1	5.08 BSC			0.20 BSC		
b	0.60	0.80	1.00	0.024	0.031	0.039	H1	6.35	6.50	6.80	0.250	0.256	0.268
b2	1.17	1.28	1.72	0.046	0.050	0.068	L	12.70	13.18	13.65	0.500	0.519	0.537
c	0.40	0.50	0.60	0.016	0.020	0.024	L1	*	*	3.95	*	*	0.156
D	15.40	15.70	16.00	0.606	0.618	0.630	L2	2.50 REF			0.098 REF		
D1	8.96	9.21	9.46	0.353	0.363	0.372	Φp	3.50	3.60	3.75	0.138	0.142	0.148
DEP	*	*	0.30	*	*	0.012	Q	2.70	2.80	3.20	0.106	0.110	0.126
E	9.66	9.97	10.28	0.380	0.393	0.405	θ1	5°	7°	9°	5°	7°	9°
E1	*	8.70	*	*	0.343	*	θ2	1°	3°	5°	1°	3°	5°
E2	9.80	10.00	10.20	0.386	0.394	0.402							

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